Diode Semiconductor Device - Page 1 of 1



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Inclosure	Material:
Glass	
Overall L	ength:
Between (	0.230 inches and 0.300 inches
Terminal	Length:
1.000 inch	nes
Overall D	iameter:
Between (	0.085 inches and 0.107 inches
Function	For Which Designed:
Zener dio	de
Joint Elec	ctronic Device Engineering Council/jedec/case Outline Designation:
Do-7	
Mounting	y Method:
Terminal	
Features	Provided:
Hermetica	ally sealed case
Semicono	ductor Material:
Silicon	
Voltage R	Rating In Volts Per Characteristic:
30.0 regi	ulator voltage
Voltage T	olerance In Percent:
-0.5/+0.5	
Current R	Rating Per Characteristic:
4.00 millia	amperes all primaries horsepower metric
Power Ra	ating Per Characteristic:
250.0 milli	iwatts small-signal input power, common-collector absolute
Maximum	n Operating Tempurature Per Measurement Point:
175.0 deg	rees celsius ambient air
Terminal	Type And Quantity:
2 uninsula	ated wire lead
Specifica	tion Data:
80131-rele	ease 2316 government specification
Shelf Life	
N/a	
Unit Of M	leasure:
Demilitari	ization:
No	
Fiig:	